Old Company Name in Catalogs and Other Documents

On April 1st, 2010, NEC Electronics Corporation merged with Renesas Technology Corporation, and Renesas Electronics Corporation took over all the business of both companies. Therefore, although the old company name remains in this document, it is a valid Renesas Electronics document. We appreciate your understanding.

Renesas Electronics website: http://www.renesas.com

April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)
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CHANNEL MOS FIELD EFFECT POWER TRANSISTOR

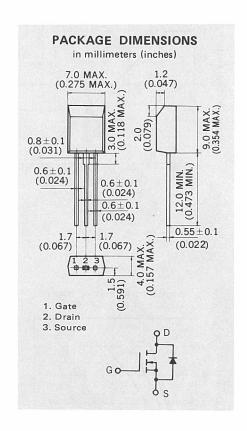
Phase-out/Discontinued

FEATURES

- Suitable for switching power supplies, actuater controls, and pulse circuits
- Low $R_{DS(on)}$ $R_{DS(on)} = 0.95 \Omega$ TYP. $(V_{GS} = 4 \text{ V}, I_D = 0.5 \text{ A})$
- No second breakdown

ABSOLUTE MAXIMUM RATINGS

Maximum Temperatures Storage Temperature -55 to +150 °C Channel Temperature..... 150 °C Maximum Maximum Power Dissipation (T_a = 25 °C) Total Power Dissipation 1.0 W Maximum Voltages and Currents (T_a = 25 °C) Drain to Source Voltage 30 V_{DSS} V V_{GSS} Gate to Source Voltage. ±20 V Drain Current (DC) ±1.0 ID(DC) Drain Current (pulse)* ±2.0 Α D (pulse) * PW \leq 300 μ s, Duty Cycle \leq 10 %



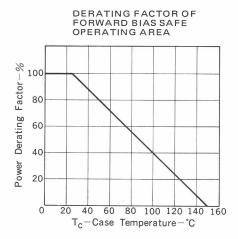
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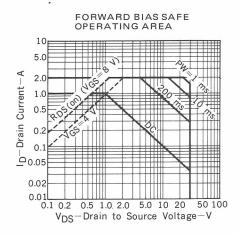
ELECTRICAL CHARACTERISTICS (T_a = 25 °C)

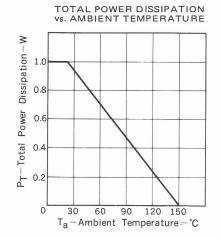
SYMBOL	CHARACTERISTIC	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
IDSS	Drain Leakage Current			10	μΑ	V _{DS} = 20 V, V _{GS} = 0
IGSS	Gate to Source Leakage Current			±100	nΑ	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0$
V _{GS(off)}	Gate to Source Cutoff Voltage	1.0		2.5	V	$V_{DS} = 10 \text{ V}, I_{D} = 1.0 \text{ mA}$
ly _{fs} l	Forward Transfer Admittance	0.4			S	V _{DS} = 10 V, I _D = 0.5 A
R _{DS(on)}	Drain to Source On-State Resistance		0.5	1.0	Ω	$V_{GS} = 10 \text{ V}, I_D = 0.5 \text{ A}$
R _{DS(on)}	Drain to Source On-State Resistance		0.95	1.5	Ω	$V_{GS} = 4.0 \text{ V}, I_D = 0.5 \text{ A}$
C _{iss}	Input Capacitance		40		pF)	
Coss	Output Capacitance		65		pF	V _{DS} = 10 V, V _{GS} = 0, f = 1 MHz
C _{rss}	Reverse Transfer Capacitance		10		pF	
td(on)	Turn-On Delay Time		60		ns	I _D = 0.5 A, V _{CC} = 25 V
t _r	Rise Time		180		ns	V _{GS(on)} = 10 V
td(off)	Turn-Off Delay Time		550		ns	$R_L = 50 \Omega$ $R_{in} = 10 \Omega$
tf	Fall Time		400		ns 🕽	110 10 22

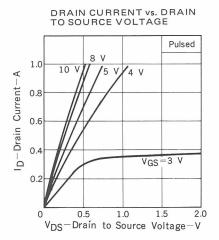


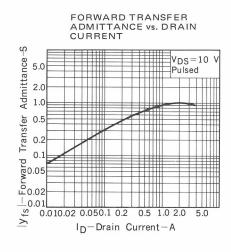
TYPICAL CHARACTERISTICS ($T_a = 25$ °C)

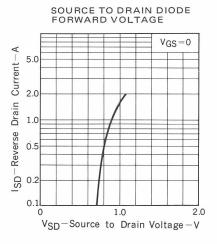


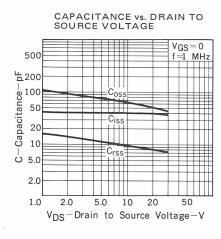


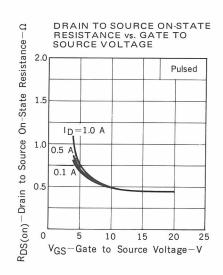


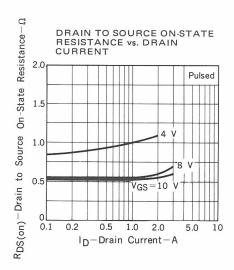


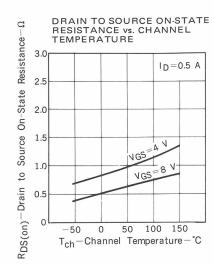


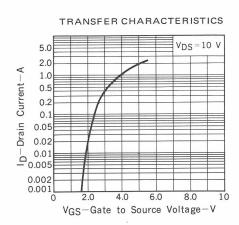


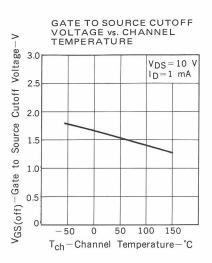




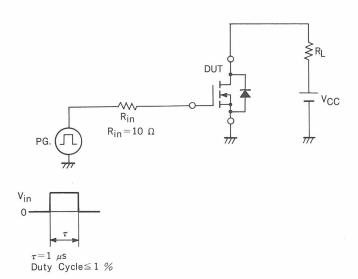


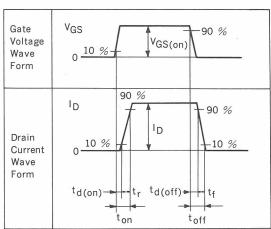






TURN-ON AND TURN-OFF TIME TEST CIRCUIT







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